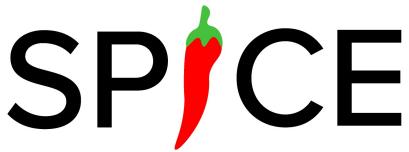


# Low Energy Event Excess in Calorimeters



Matt Pyle  
EXCESS 22  
2/15/21



# Outline

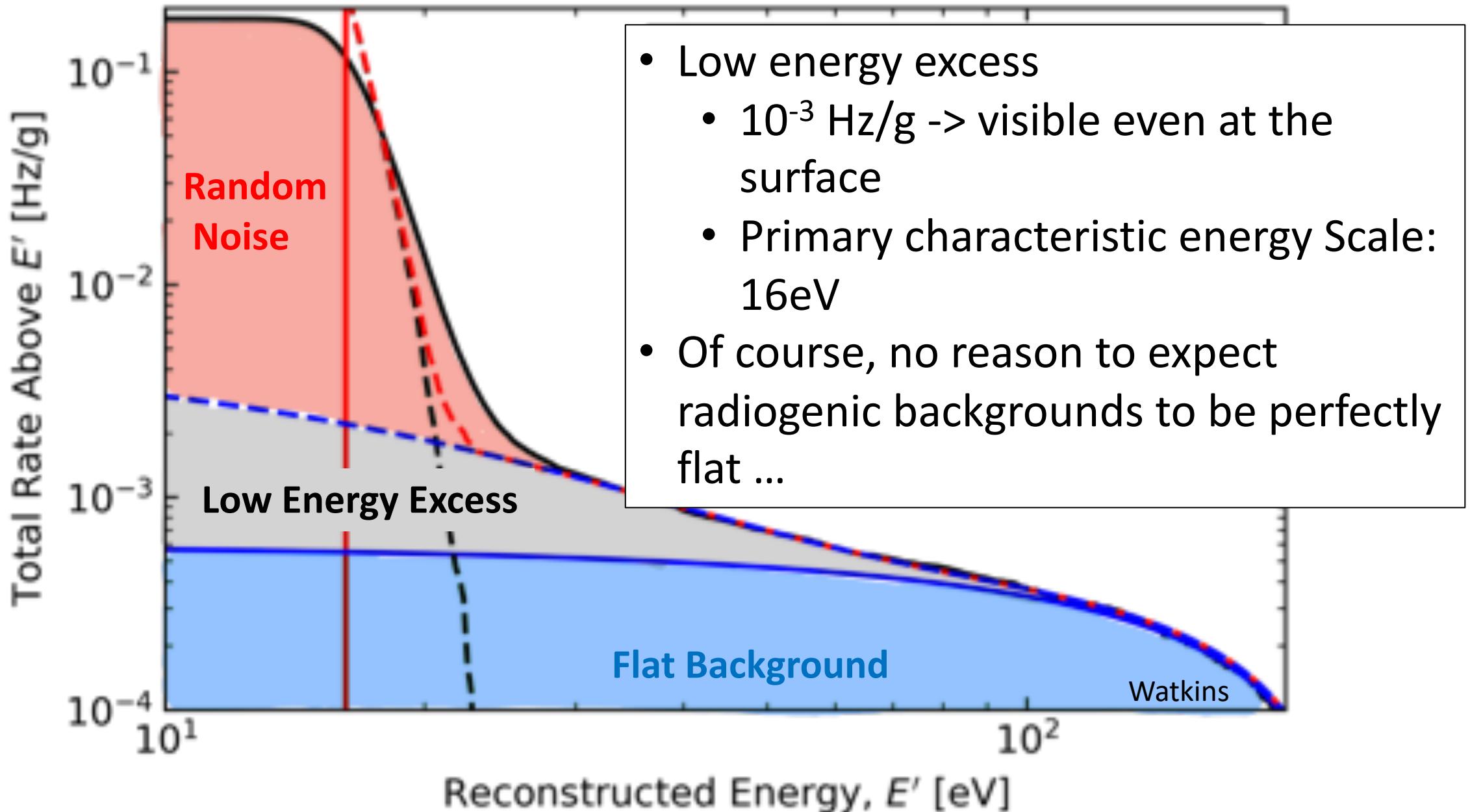
1. Summary of low energy excess measurements and testing this information vs various hypotheses.
2. Solutions to the low energy excess problem
  - A. Direct mitigation
  - B. Discrimination using multiple channels
  - C. Separation in Energy

# Cryogenic Photon Detector (CPD)

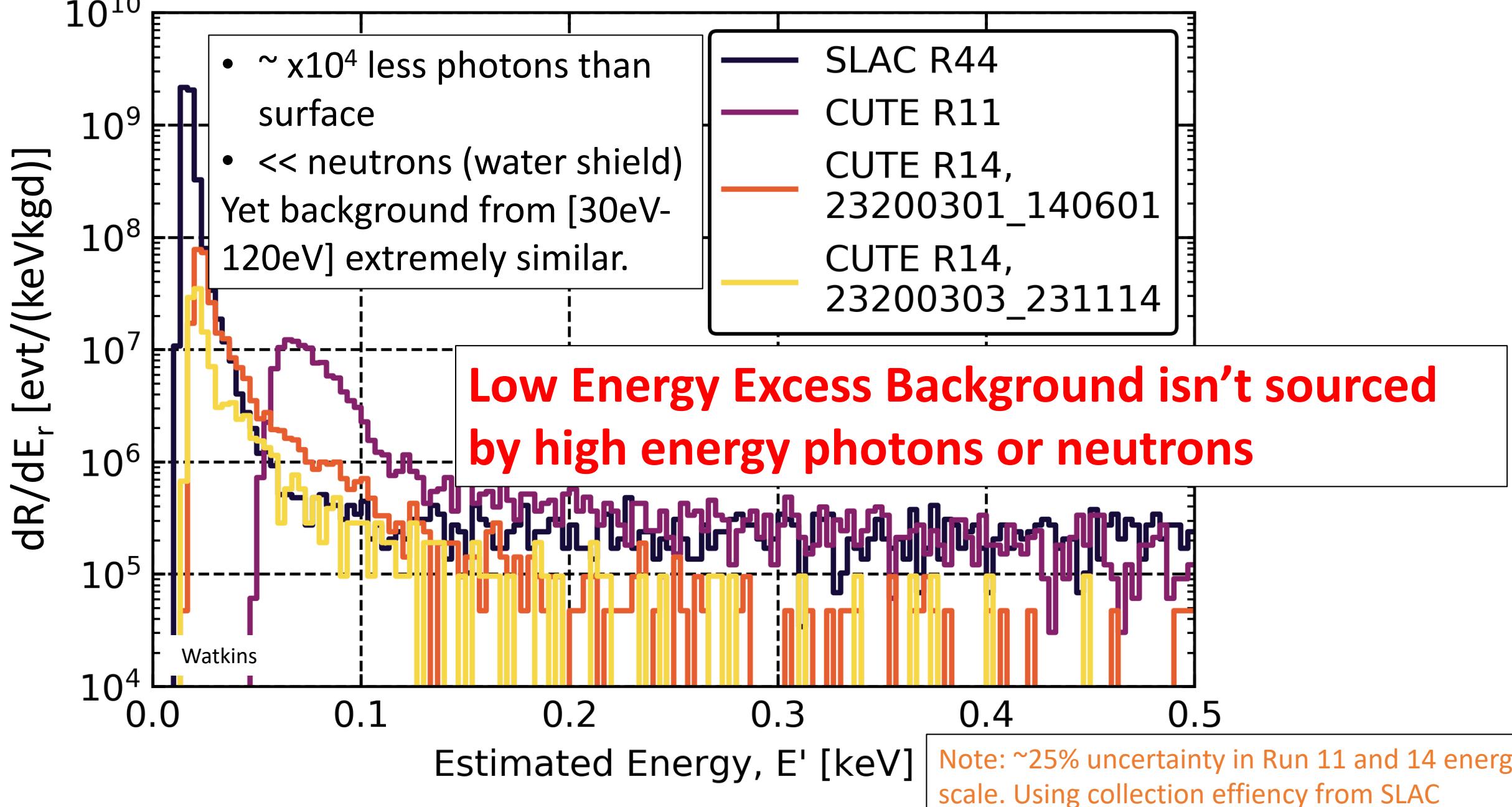


- CPD: 10g 45cm<sup>2</sup>x1mm Si Athermal Phonon Detector Designed for Light Collection
- $\sigma_{pt} = 3.9\text{eVt}$
- Run both above (SLAC) and below ground (CUTE @ SNOLAB) jointly by the SuperCDMS and CPD collaborations
- Technical Paper: 2009.14302 (APL)
- SLAC DM Search: 2007.14289 (PRL)

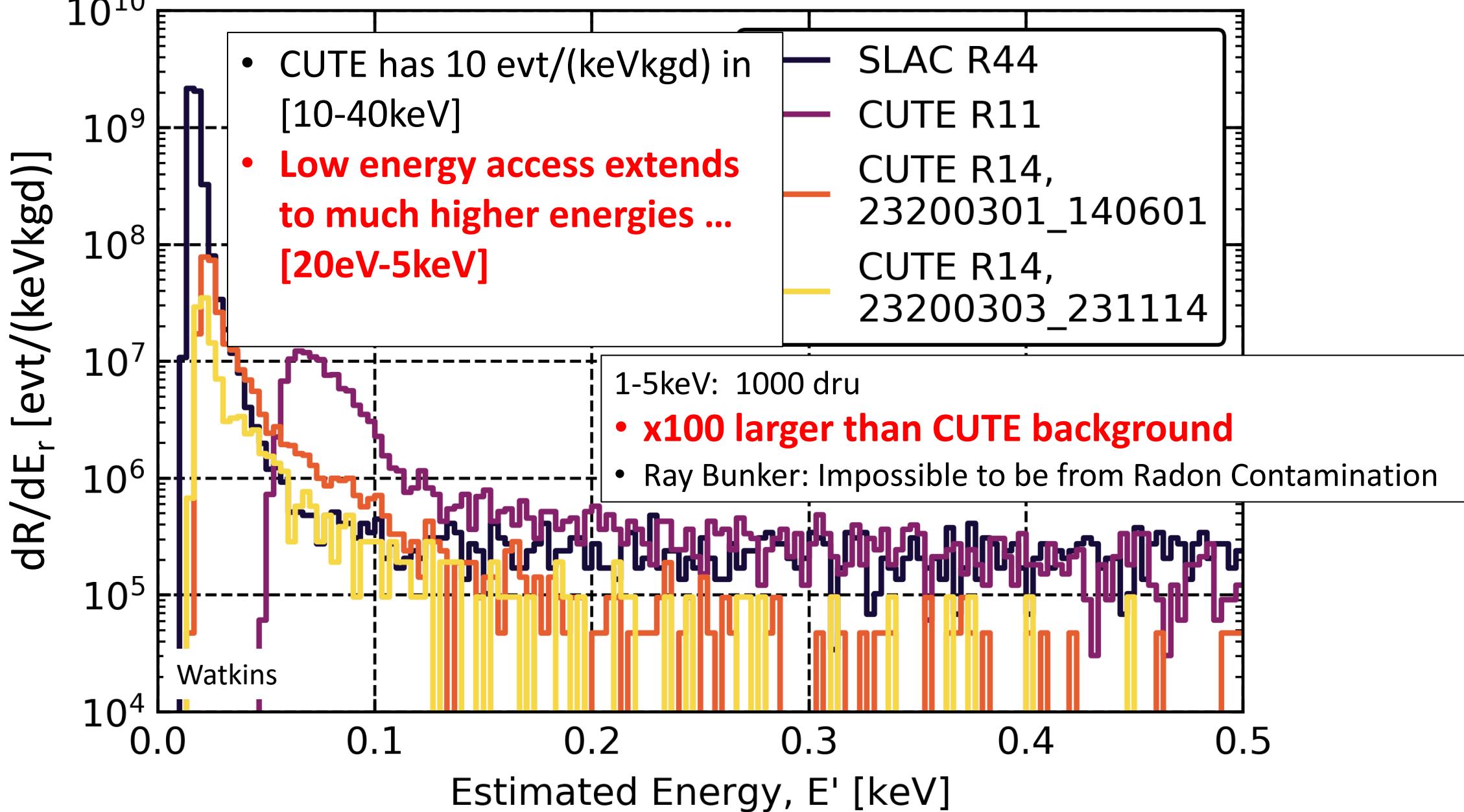
# Low Energy Excess Event Rate: CPD



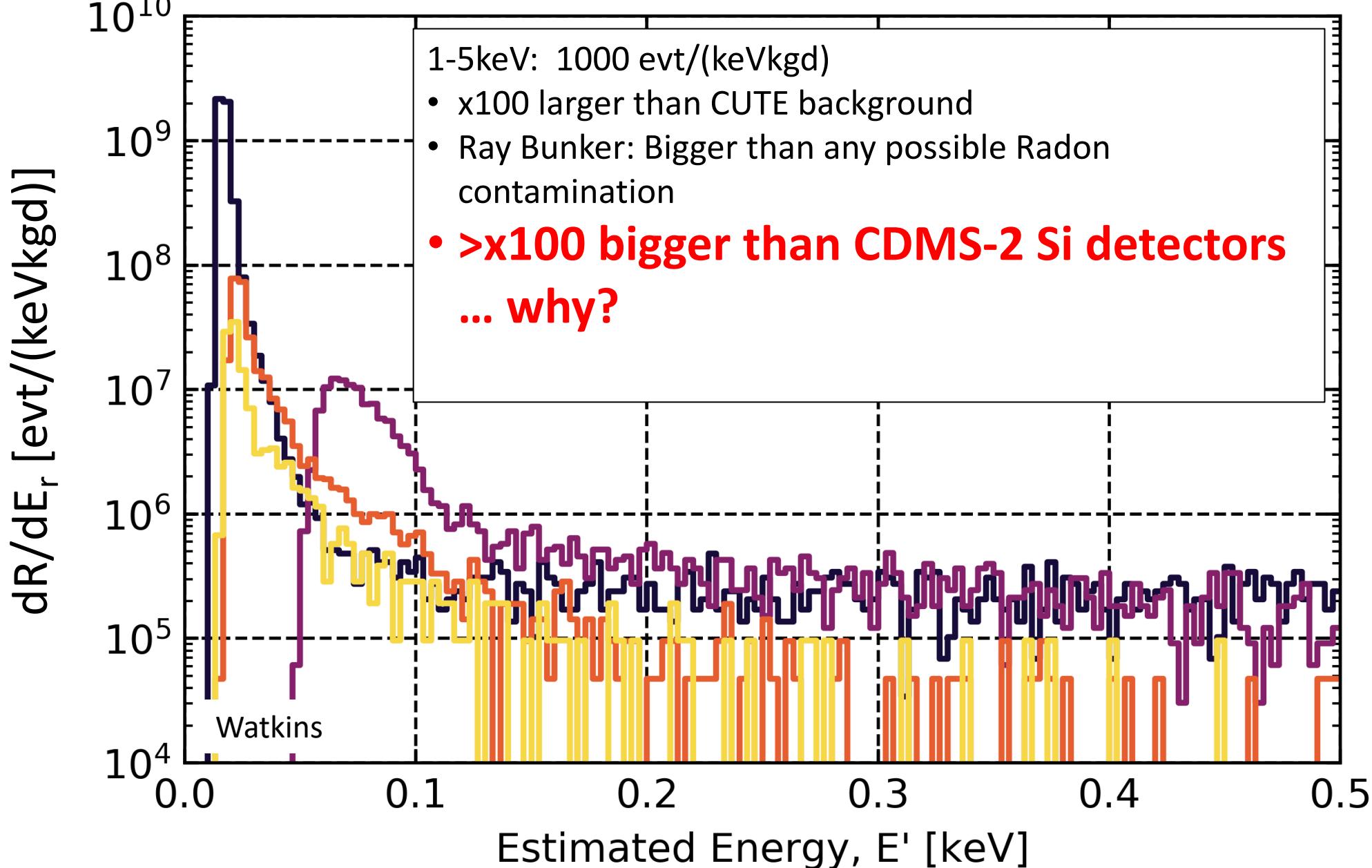
# 1) Go Underground and Shield: Excess Still There



## 2) Go Underground and Shield: High Energy Excess

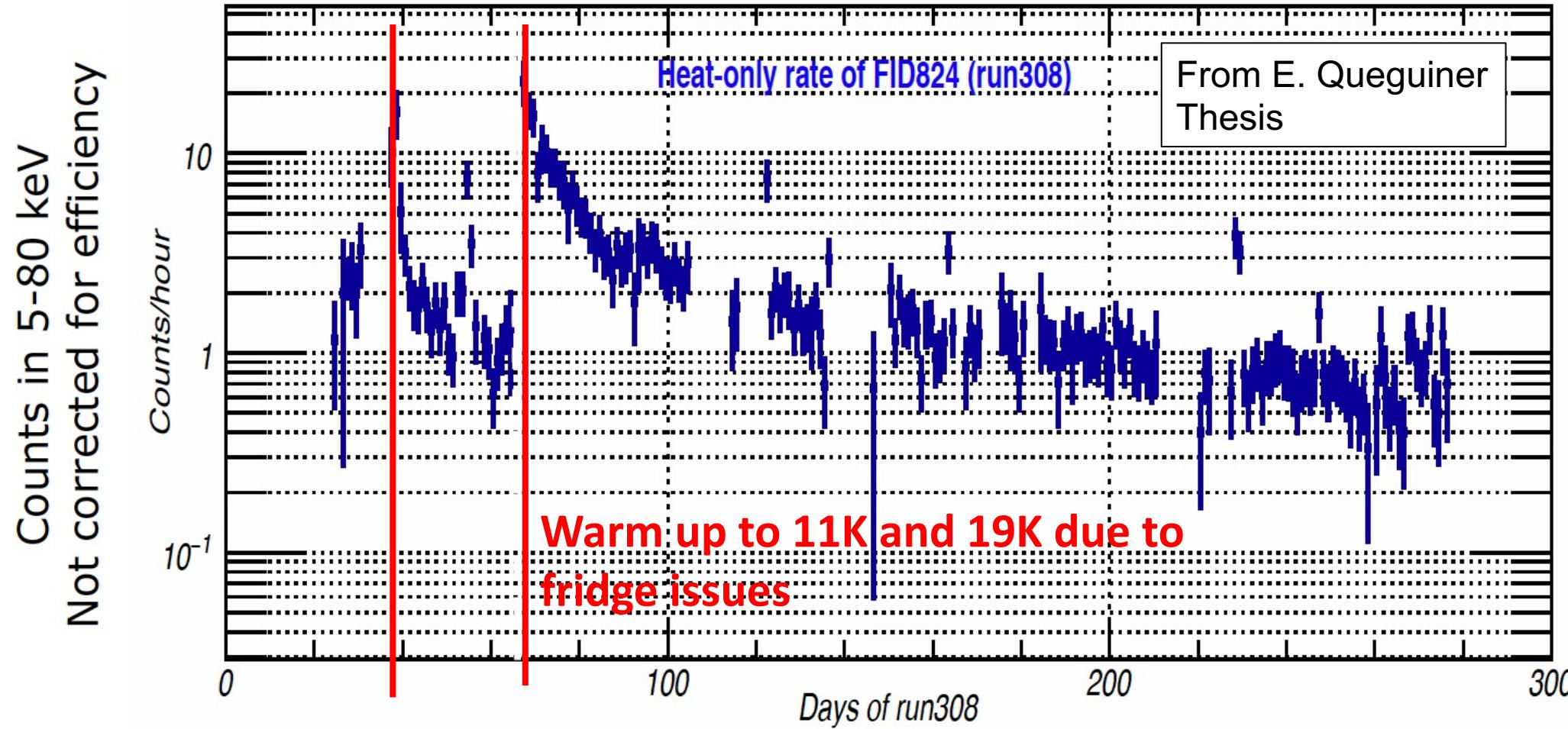


### 3) Go Underground and Shield: High Energy Rate >> CDMS2



# 4) Variation with Time Since Cooldown

EDELWEISS Low Energy Excess (FID 824)

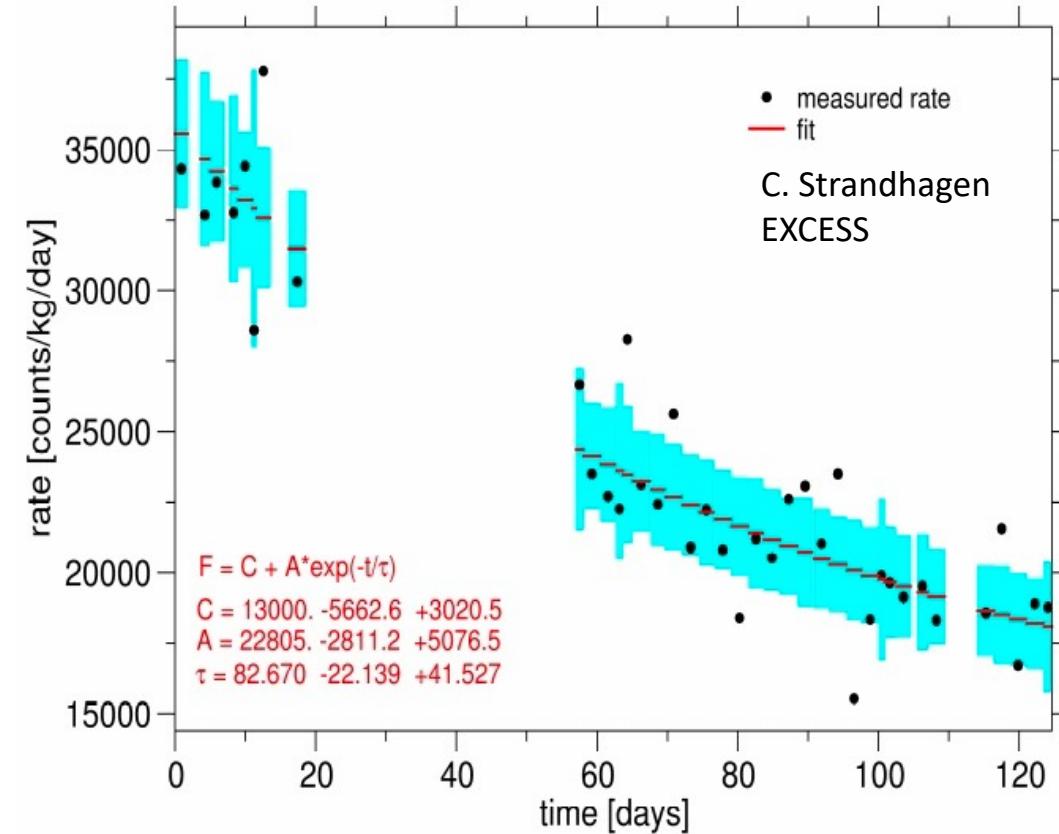


**Most Important Question:**

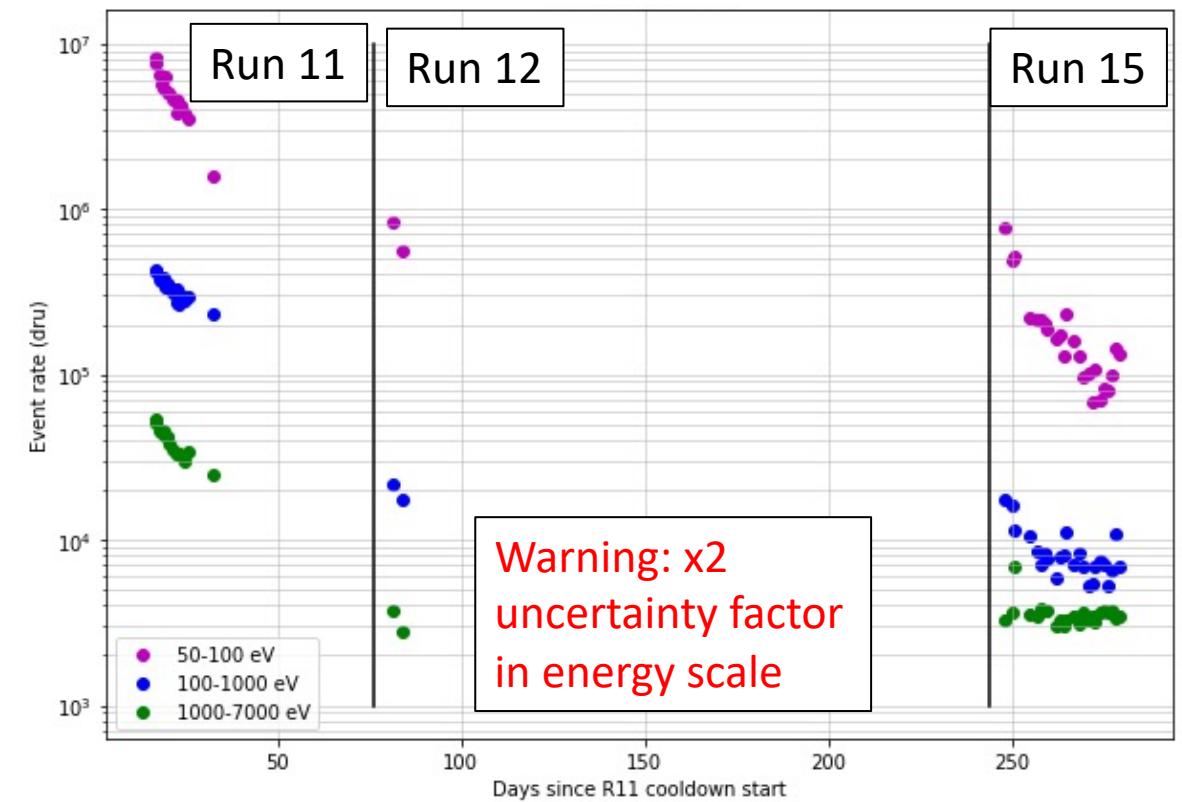
**What background sources can vary with time since cooldown?**

# 4) Variation with Time Since Cooldown

CRESST Sapphire



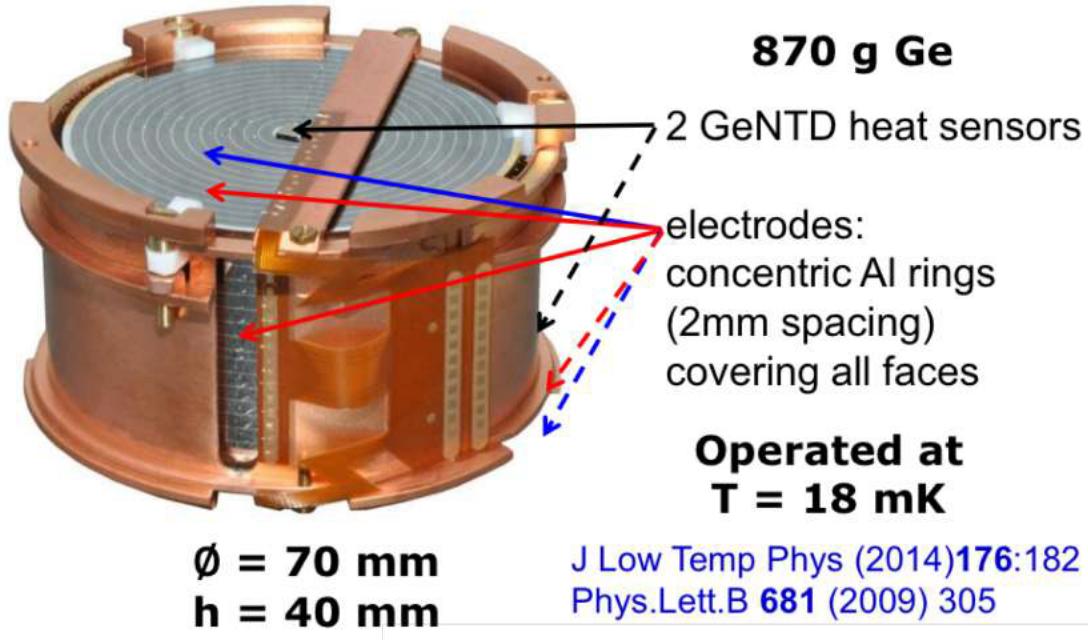
CPD@CUTE



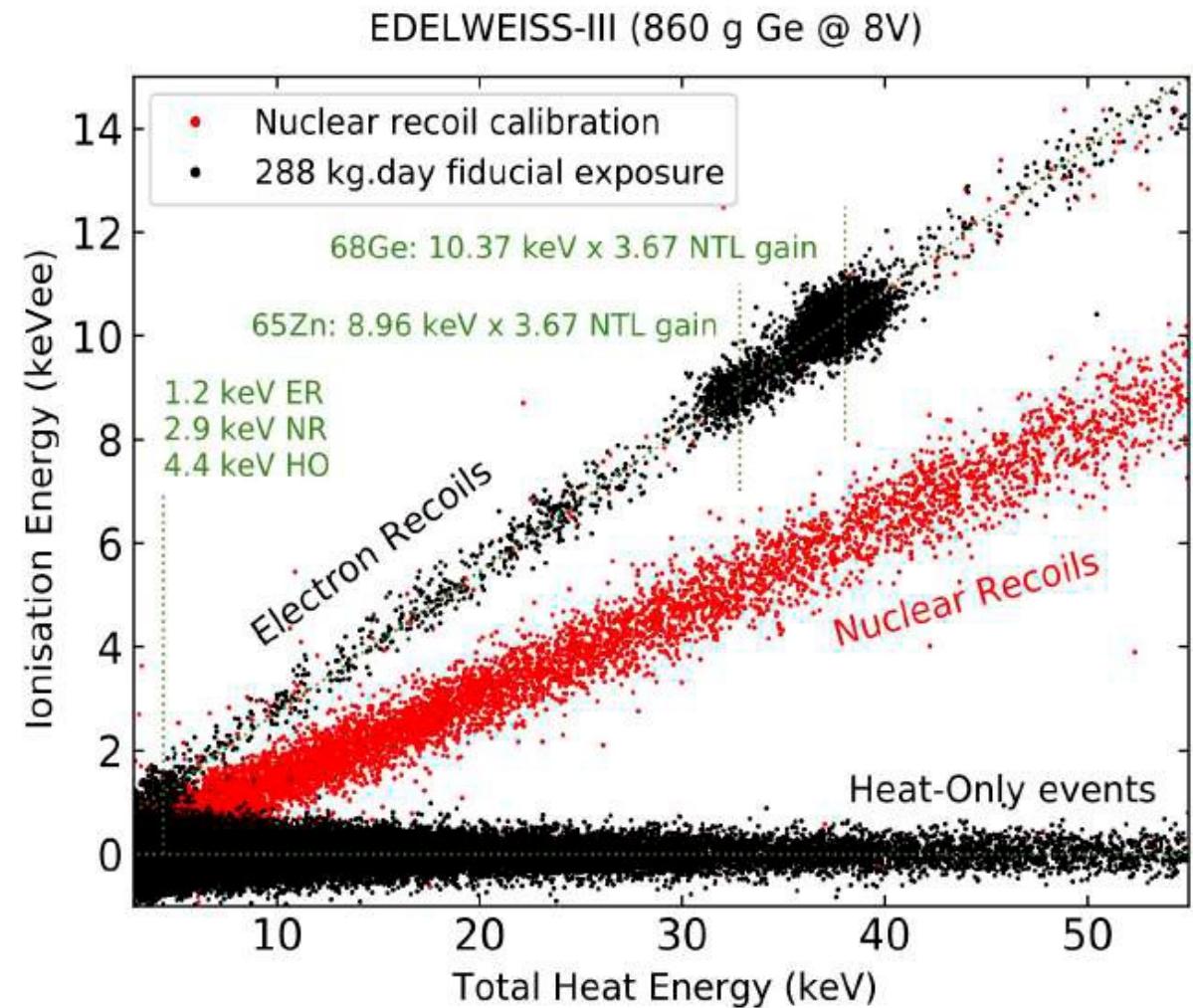
Both CRESST and CPD have low energy excess that vary with time

- Interestingly: decrease seems to be additive with cold time for CPD, but not for EDELWEISS ... weird

# 5) Low Energy Excess is Non-ionizing



- EDELWEISS interleaved detectors measure both phonons (NTD) and ionization production
- Large no ionization background of unknown origin out to pretty high energies

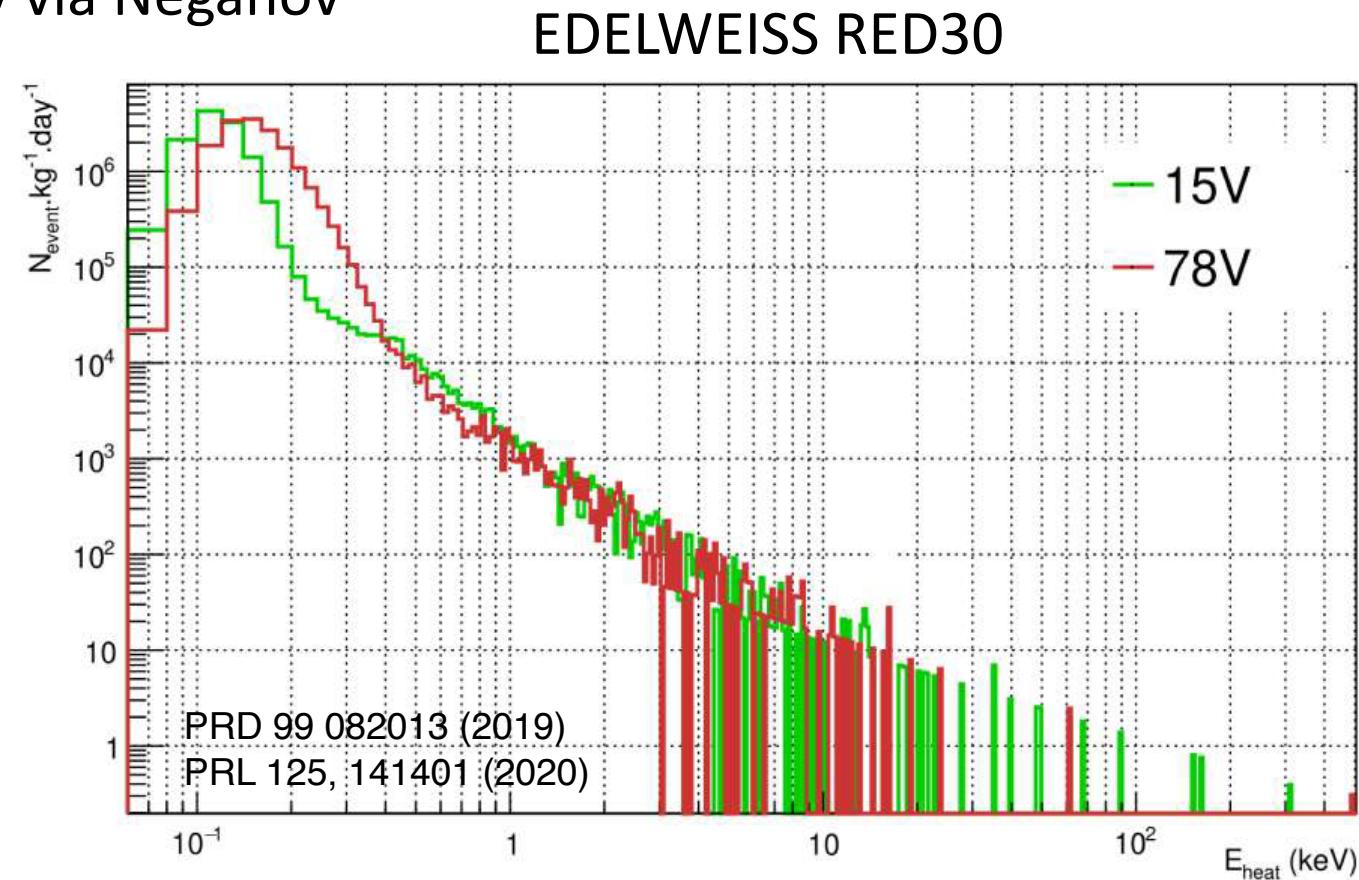
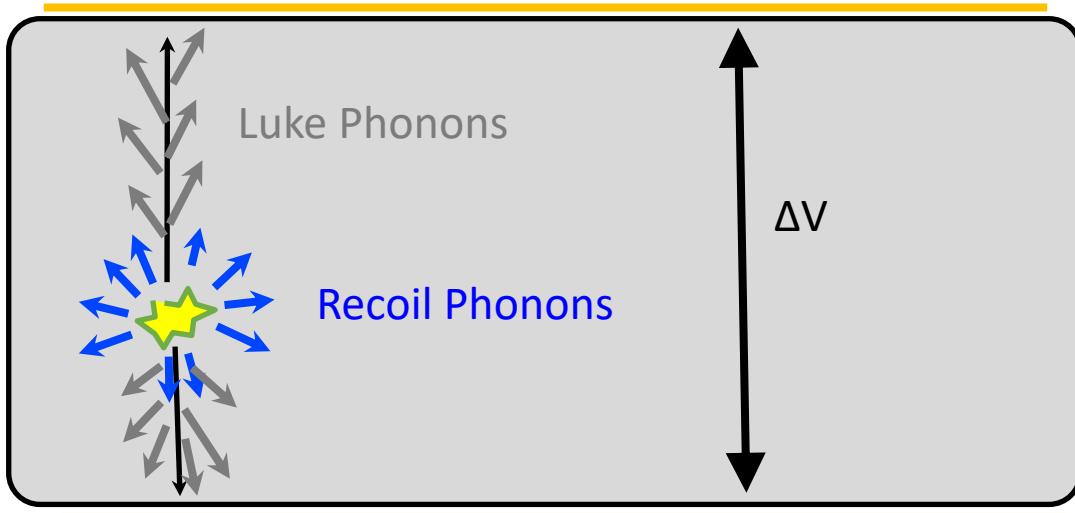


From J. Gascon /EDELWEISS

# 5) Low Energy Excess is Non-ionizing

- Drifting charges release kinetic energy via Neganov Tiramov Luke (NTL) Phonon Production

- $$\begin{aligned} E_{total} &= E_{recoil} + E_{NTL} \\ &= E_{recoil} + n_{eh}e\Delta V \end{aligned}$$



Lack of stretching means there is very little ionization in these events.

Probably same conclusion for SuperCDMS except more sketchy (not same detector)

# Low Energy Excess Fact Summary:

	CPD / CDMS	EDELWEISS	CRESST
1) Same above and below ground	mostly	mostly	
2) Broad Energy Scale	Yes	Yes	
3) Rate varies significantly between detectors	Yes	Yes	Yes
<b>4) Time variation with time since cooldown</b>	Yes (since run 11?)	Yes	Yes (partial)
5) Low Energy Excess is Non-ionizing	Probably?	Yes	?

- ~~Daughters from high energy photons/ neutrons~~

- 1) ~same rate above ground and at CUTE
- 2) Time since cooldown variation
- 3) Zero ionization

- ~~Radon or any surface contamination~~

- 3) Time since cooldown variation
- 2) Energy spectrum/shape (radon)
- 5) Rate ... just too big (radon)

- ~~EMI Noise~~

- 6) Phonon pulse shape

- ~~Metastable electronic states:~~

- 2) Energy Scale: the scale of condensed matter is eV scale 100eV excess event must be multiple particles rearranging

- **Stress Induced Microfractures: matches all facts**

**3) Time since cooldown variation**

**2) Energy Scale**

# Warning: Hypothesis Testing

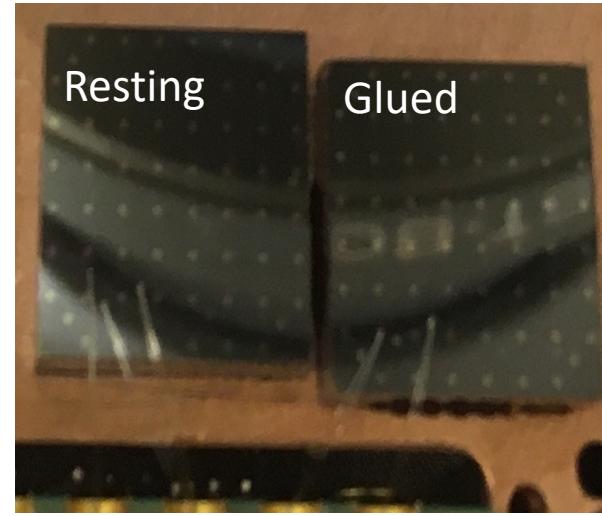
- Low energy excess could have subdominant sources that don't meet all of these facts:
  - Example: Only a portion of their low energy excess displays time since cooldown dependence (CRESST).
- Low energy excess at different energy scales could have different sources
  - Perhaps the 20-120eV excess rate is EMI while the 120eV-5keV background is something else.
- (I will talk a bit about mitigating some of these other potential sources later)

# Additional Evidence: CDMS-2 vs CPD

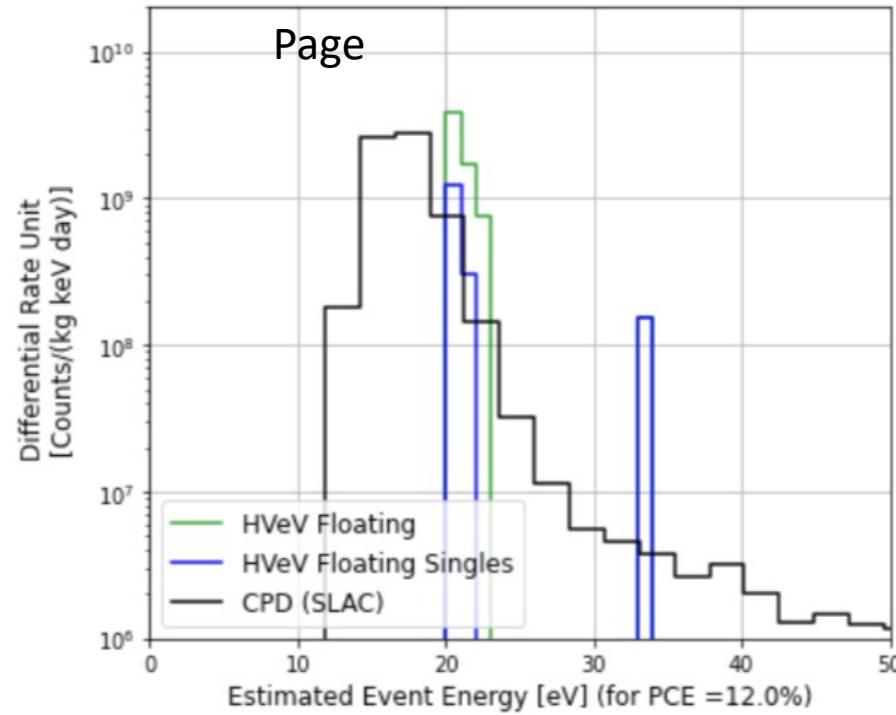
- CPD has ~ x500 higher backgrounds in the 1-5keV range than CDMS2-Si
- Differences:
  - Radon control
  - 1cm vs 1mm thick
  - CPD clamping placed enough stress on the 1mm Si wafer to visibly distort the surface.
- Consistent with the hypothesis of stress induced microfractures



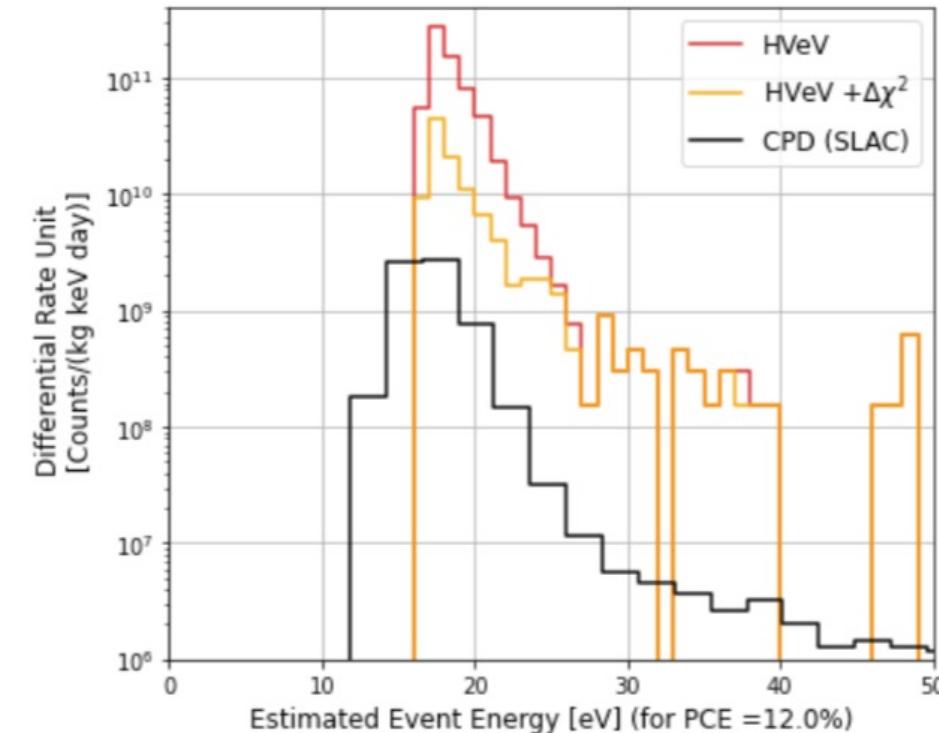
# Additional Evidence: GE Varnish Studies



Resting Chip



Glued Chip



Thermal stress in GE varnish produce  $5\text{Hz}/\text{cm}^2$  of low energy microfractures

# Mitigation for Stress Induced Microfracture Events

# Mitigation

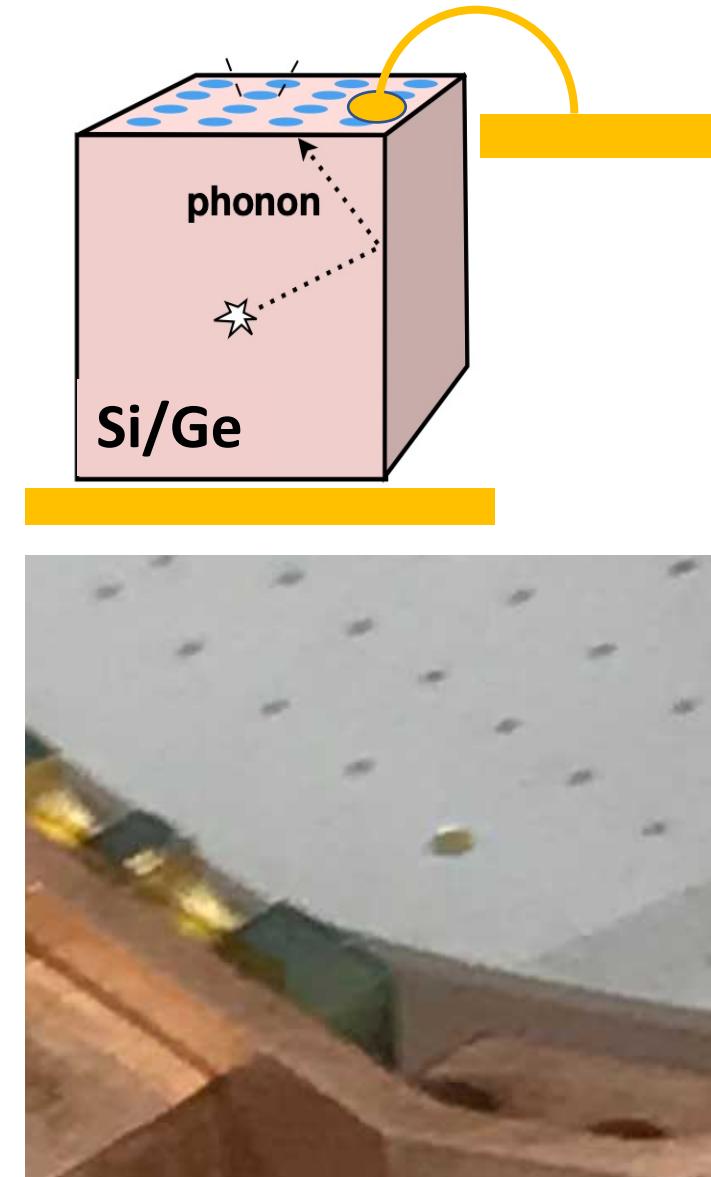
- Remove/Lower all possible sources of stress in your detector!
- Problem: This is hard work with lots of ancillary side effects

## Example: Complications with removing stress

- Thermal conductance to bath scales with clamp normal force

- TES bias power is dissipated through clamps ... if not removed our high bandwidth athermal phonon sensors become low bandwidth thermal calorimeters.

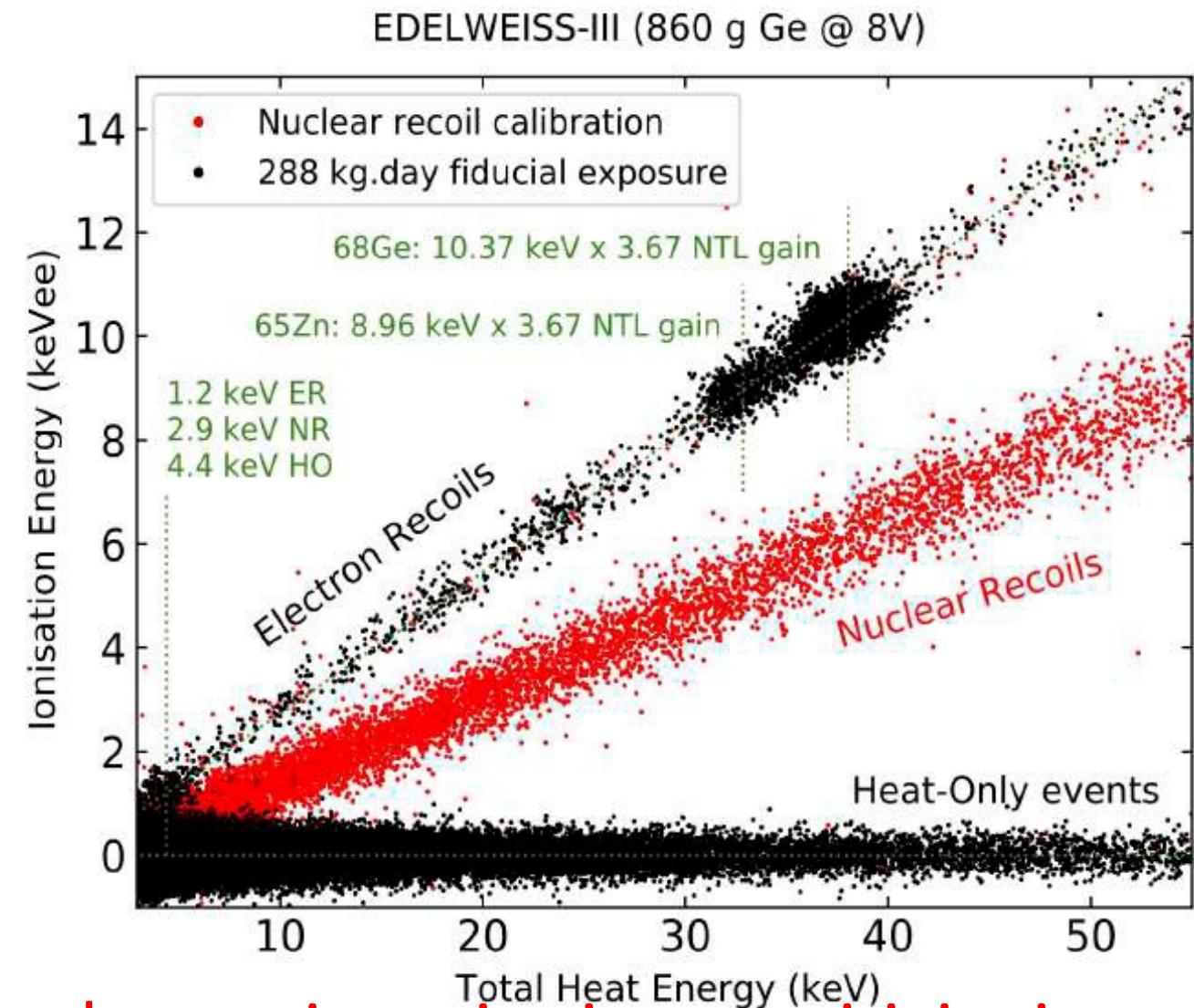
- Solution: add gold pad + wirebond thermal link to athermal phonon sensor design



Discrimination of Ionizing  
Events vs Non-Ionizing  
Events (like microfractures)

# Discrimination: Real Recoils vs Microfracture Events

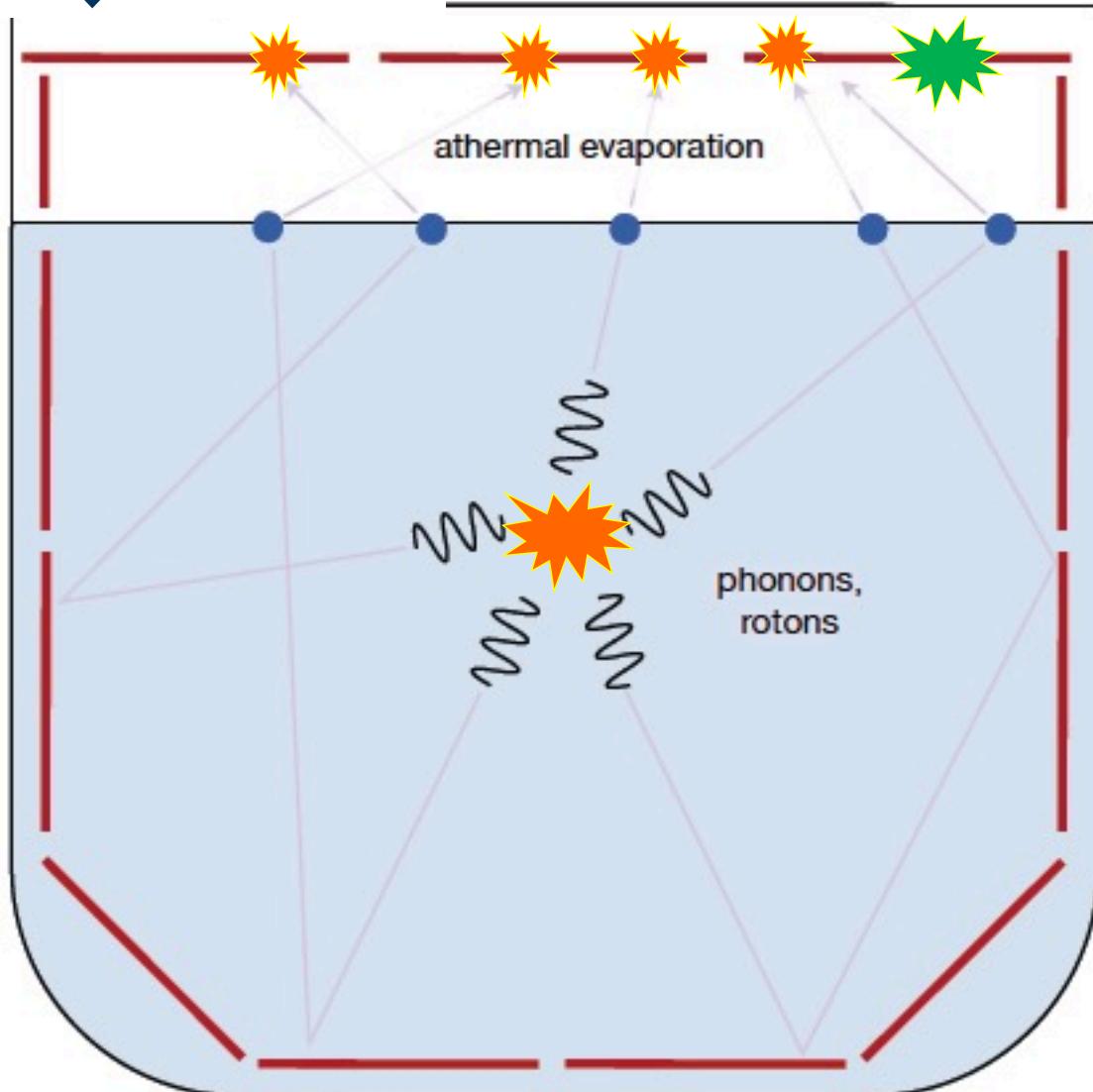
- Electronic Recoils and Nuclear Recoils for DM with  $M_{DM} > O(200\text{MeV})$  produce ionization
- Design an experiment that independently measures phonons and electronic excitations



Problem: single photon / few electronic excitation sensitivity is challenging



# <sup>2</sup>HeRALD Helium Roton Apparatus for Light Dark matter

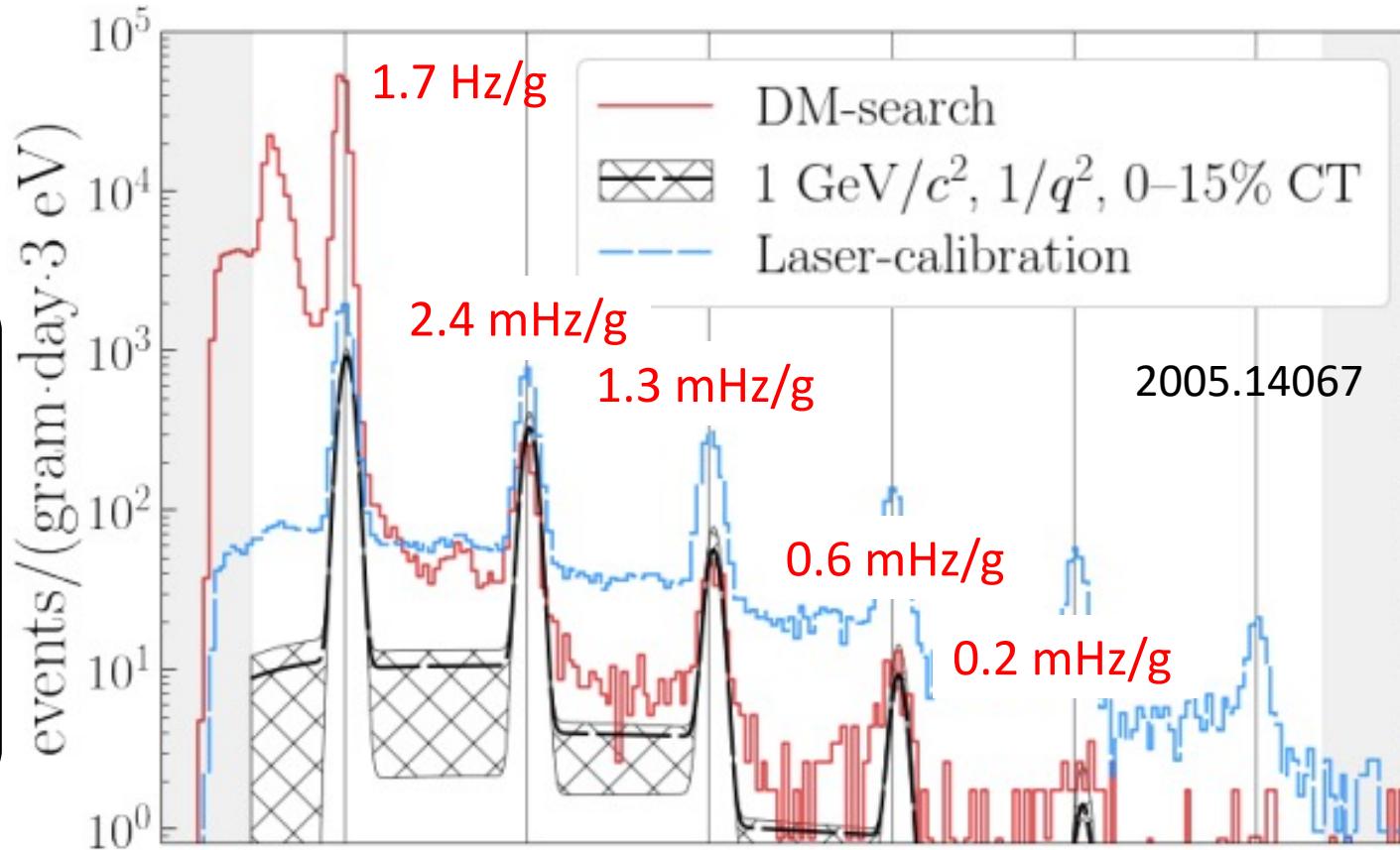
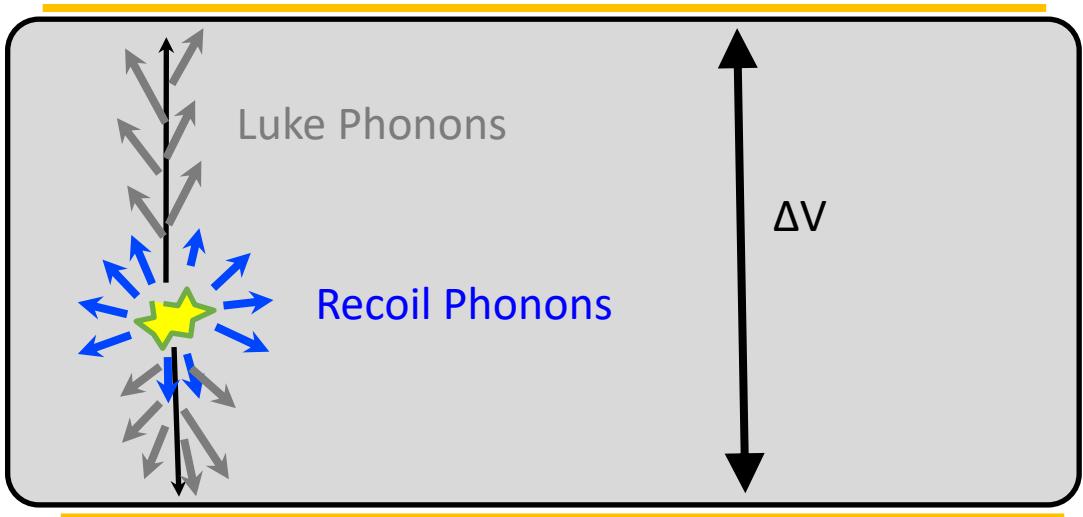


- Superfluid Helium: it's a liquid ... no stress microfractures
  - Multiple Pixel Coincidence for He DM events
    - microfractures (low energy excess) uncorrelated between detectors
    - DM recoiling off of He: produces signals in multiple roton detectors -> require multiple pixel coincidence for He events
  - Pulse Shape: Helium is slow!
- HeRALD is a hard experiment ... but it has multiple background rejection techniques that crystals don't have**

# Separating Signal from Low Energy Excess Backgrounds

# Separation in Energy: NTL Amplification

$$\begin{aligned}E_{total} &= E_{recoil} + E_{NTL} \\&= E_{recoil} + n_{eh}e\Delta V\end{aligned}$$

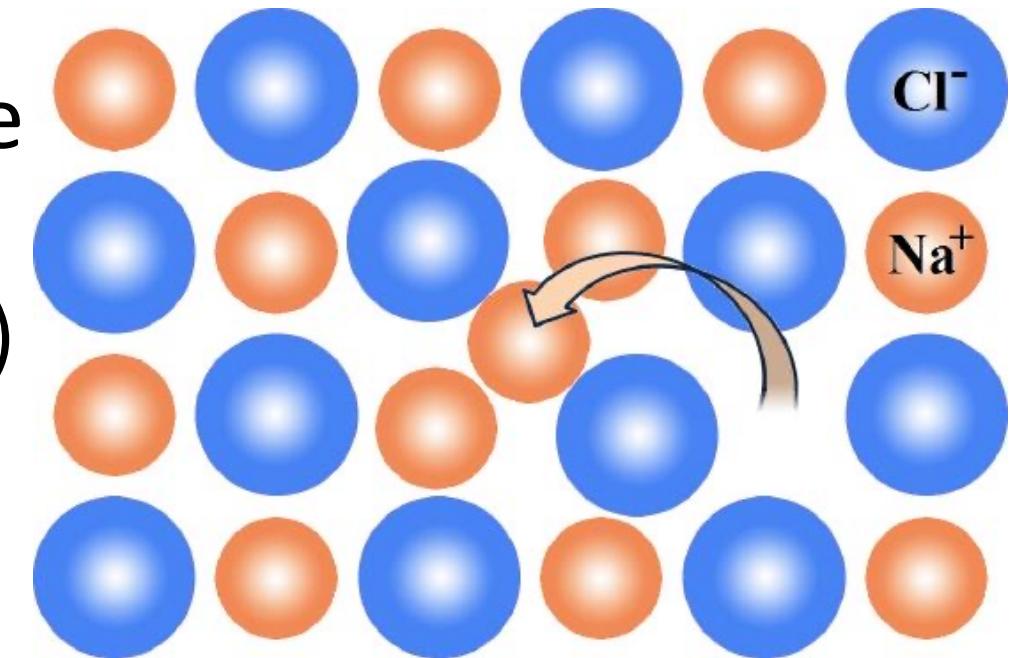


Just boost the ionizing signal above the low energy excess with TNL Gain

Problem: You become sensitive to charge leakage tunneling 😞

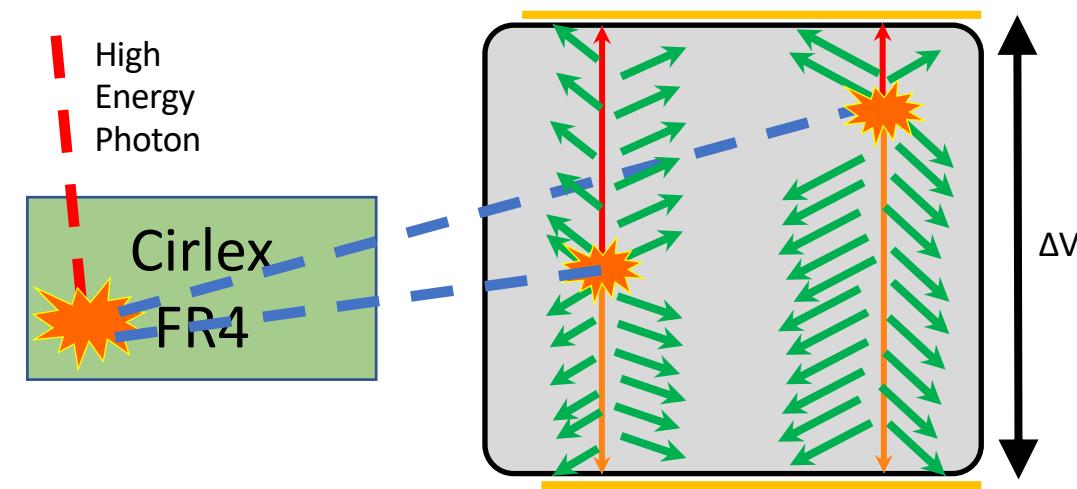
# Separation in Energy: What happens below 0(eV)?

- No low energy excess measurements below 20eV currently
- BIG QUESTION: Is there a lower energy threshold to the low energy excess? If yes, just look below this threshold
- Why would we expect a low energy threshold? Crystal stuff happens at the eV scale
  - Frenkel Pair Crystal Defect has O(4eV) in Si
  - Electronic excitations O(eV)
- Problem: Designing detectors with 100meV thresholds



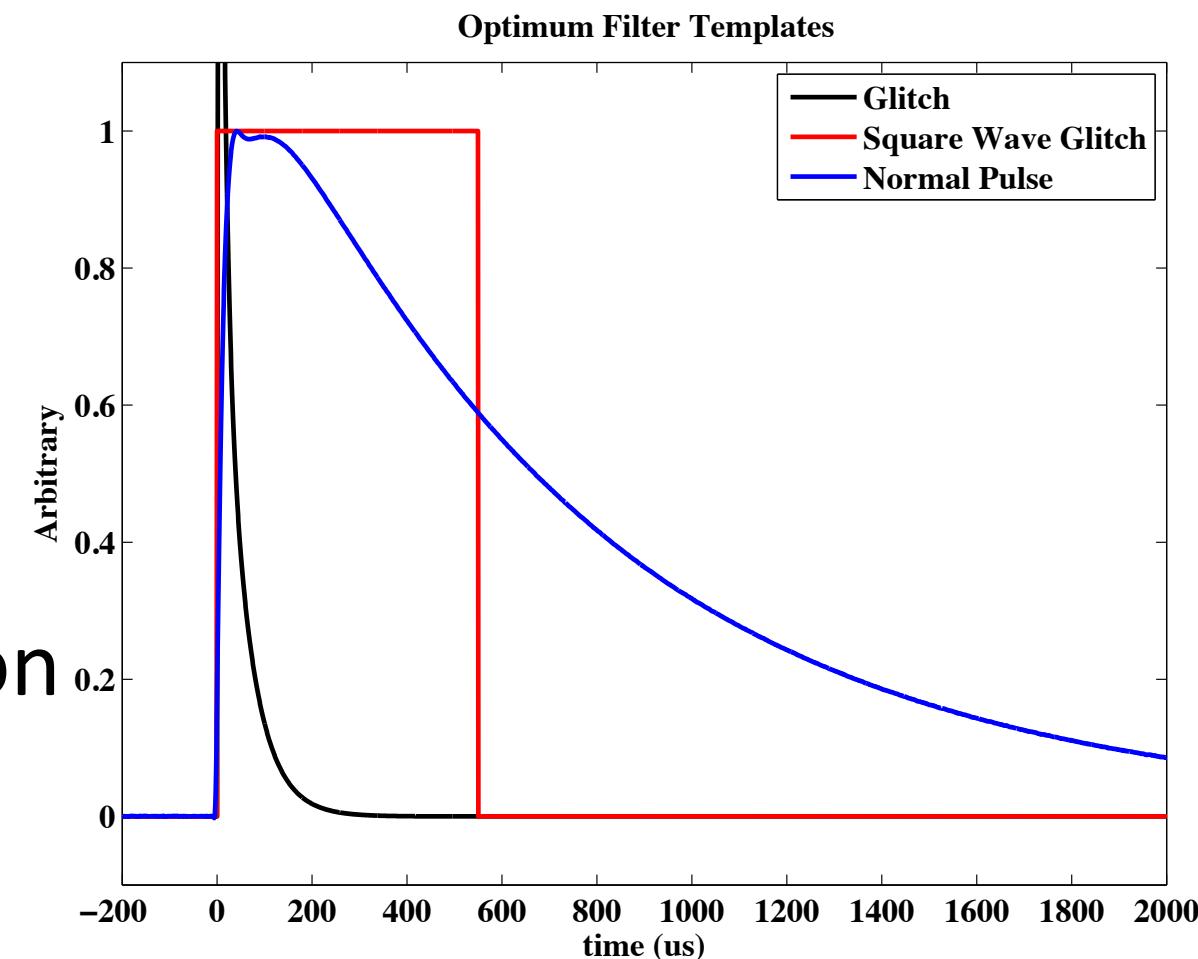
# Other Possible Background Sources: Photon Sourced

- Events sourced by high energy photons
  - SuperCDMS HVeV, SENSEI (2011.13939)
  - Single Phonon Backgrounds (2112.09702)
- Solution:
  - Get rid of non-active insulating materials in optical cavity  $\rightarrow \times 10^3$  reduction
  - Get rid of photon backgrounds  $10^4$  dru  $\rightarrow 1$  dru  $\rightarrow \times 10^4$  reduction
  - $4\pi$  Active Veto  $\rightarrow \sim \times 10^2$  reduction
- I think this is a solveable problem! Note:  
more challenging for CCDs because of the lack of timing information



# Other Possible Backgrounds: EMI

- Near Threshold “Events” could be non-stationary EMI
- Unlikely, EMI is usually correlated ...
- Solutions:
  1. Pulse shape Discrimination:  
make dirac-delta EMI pulses look different from phonon signals (you can control phonon pulse shapes via fractional sensor coverage)
  2. Faraday Cages!



Other Possible Backgrounds: ?

# Conclusions

1. A substantial component (but potentially not all) of the low energy background is:
  - Independent of photon/neutron backgrounds
  - Non-ionizing
  - Varies with time since cooldown
  - Energy scales  $\gg$  condensed matter scales

**This feels like stress induced microfractures**

2. Solutions to microfractures
  - Mitigation
  - Discrimination
  - **Separation in Energy**